

Absolute Maximum Ratings, Pre-Biased NPN Transistor, Q₁ (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage	V _{CC}	50	V
Input Voltage	V _{IN}	-10 to +40	V
Output Current	I _O	30	mA
Collector Current	I _C	100	mA

Absolute Maximum Ratings, Pre-Biased PNP Transistor, Q₂ (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Supply Voltage	V _{CC}	-50	V
Input Voltage	V _{IN}	-40 to +6	V
Output Current	I _O	-100	mA
Collector Current	I _C	-100	mA

Thermal Characteristics (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	150	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{θJA}	833	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Note: 5. For the device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

Electrical Characteristics, Pre-Biased NPN Transistor, Q₁ (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	(Note 6) V _{I(OFF)}	0.5	—	—	V	V _{CC} = 5V, I _O = 100μA
	(Note 7) V _{I(ON)}	—	—	3	V	V _O = 0.3V, I _O = 2mA
Output Voltage	V _{O(ON)}	—	0.1	0.3	V	I _O / I _I = 10mA/0.5 mA
Input Current	I _I	—	—	0.18	mA	V _I = 5V
Output Current	I _{O(OFF)}	—	—	0.5	μA	V _{CC} = 50V, V _I = 0V
DC Current Gain	G _I	68	—	—	—	V _O = 5V, I _O = 5mA
Gain-Bandwidth Product (Note 8)	f _T	—	250	—	MHz	V _{CE} = 10V, I _E = -5mA, f = 100MHz
Input Resistance	R ₁	32.9	47	61.1	kΩ	—
Resistance Ratio	R ₂ /R ₁	0.8	1	1.2	—	—

Notes: 6. The device is guaranteed to be in "OFF" state with V_{I(OFF)} up to 0.5V.
7. The device is guaranteed to be in "ON" state with V_{I(ON)} starting from 3V.
8. Characteristic of Transistor – for reference only.

Electrical Characteristics, Pre-Biased PNP Transistor, Q₂ (@T_A = +25°C unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	(Note 9) V _{I(OFF)}	-0.3	—	—	V	V _{CC} = -5V, I _O = -100μA
	(Note 10) V _{I(ON)}	—	—	-1.4	V	V _O = -0.3V, I _O = -1mA
Output Voltage	V _{O(ON)}	—	-0.1	-0.3	V	I _O / I _I = -5mA/-0.25 mA
Input Current	I _I	—	—	-0.88	mA	V _I = -5V
Output Current	I _{O(OFF)}	—	—	-0.5	μA	V _{CC} = -50V, V _I = 0V
DC Current Gain	G _I	68	—	—	—	V _O = -5V, I _O = -5mA
Gain-Bandwidth Product (Note 11)	f _T	—	250	—	MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz
Input Resistance	R ₁	7	10	13	kΩ	—
Resistance Ratio	R ₂ /R ₁	3.7	4.7	5.7	—	—

Notes: 9. The device is guaranteed to be in "OFF" state with V_{I(OFF)} up to -0.3V.
10. The device is guaranteed to be in "ON" state with V_{I(ON)} starting from -1.4V.
11. Characteristic of Transistor – for reference only.

Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$ unless otherwise specified.)

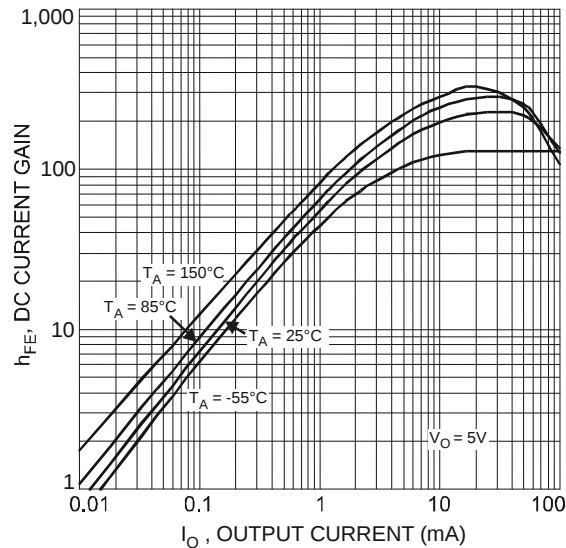


Fig. 1 Typical DC Current Gain vs. Output Current (Q1, NPN)

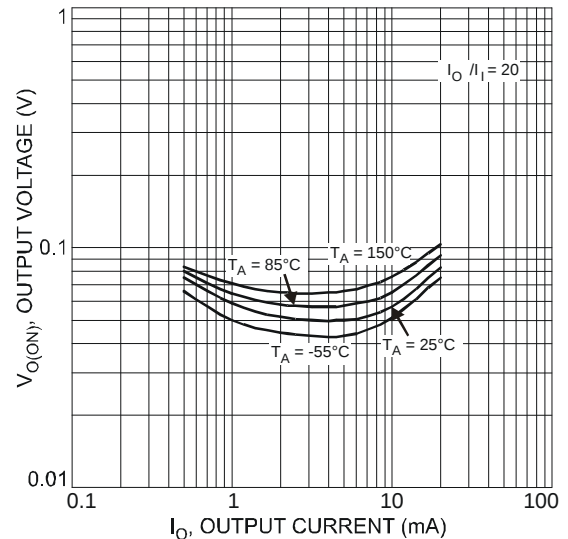


Fig. 2 Typical Output Voltage vs. Output Current (Q1, NPN)

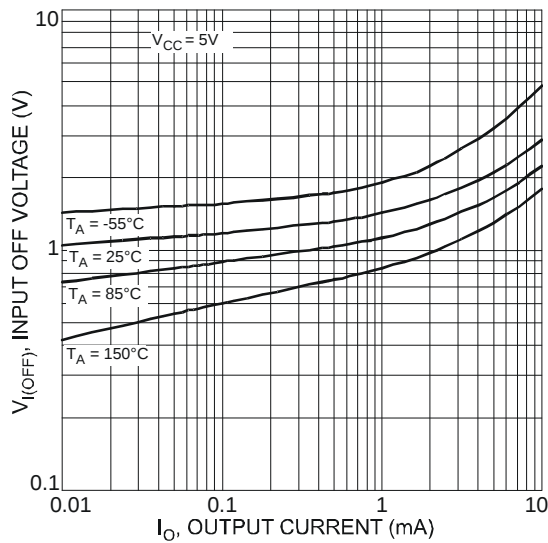


Fig. 3 Typical Input OFF Voltage vs. Output Current (Q1, NPN)

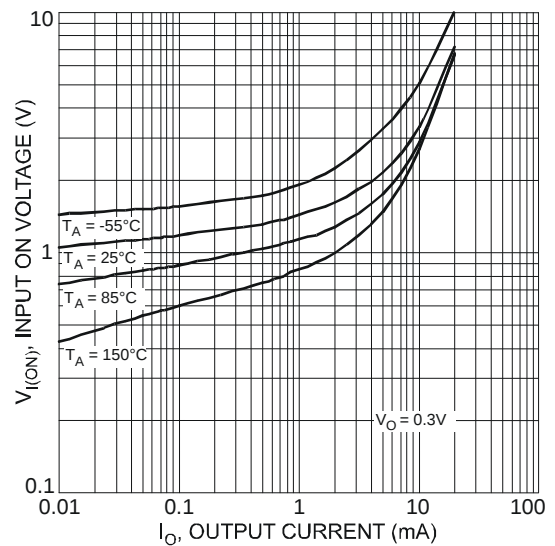
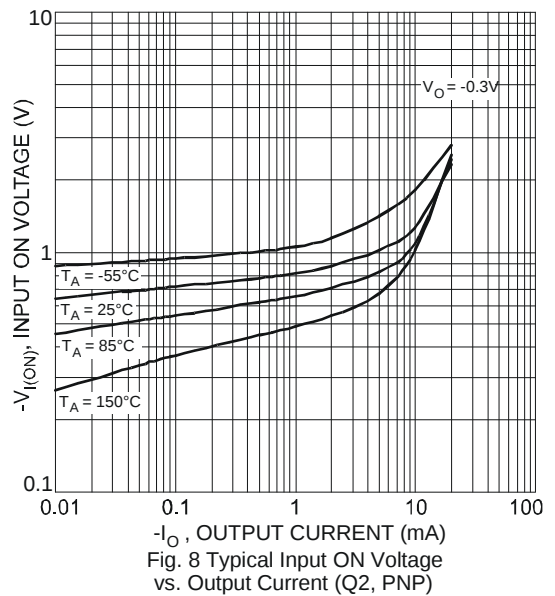
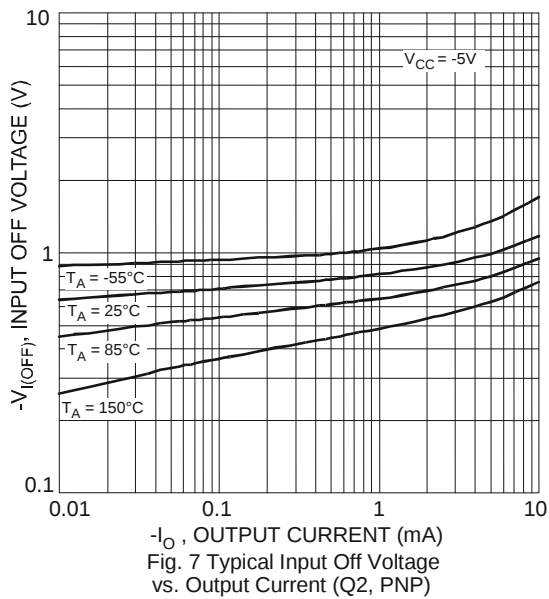
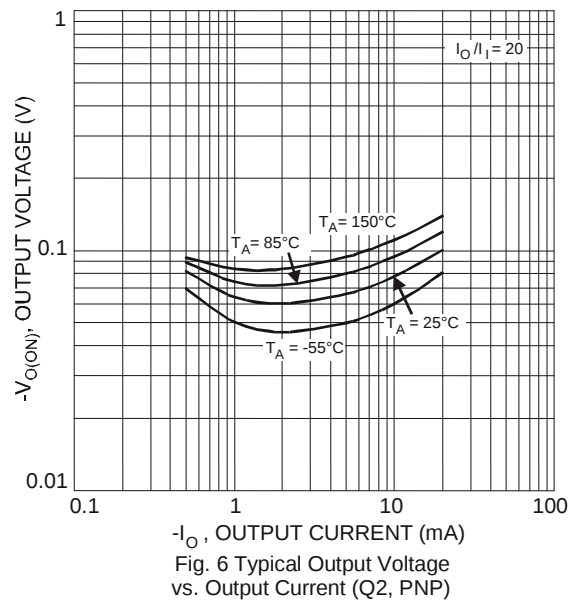
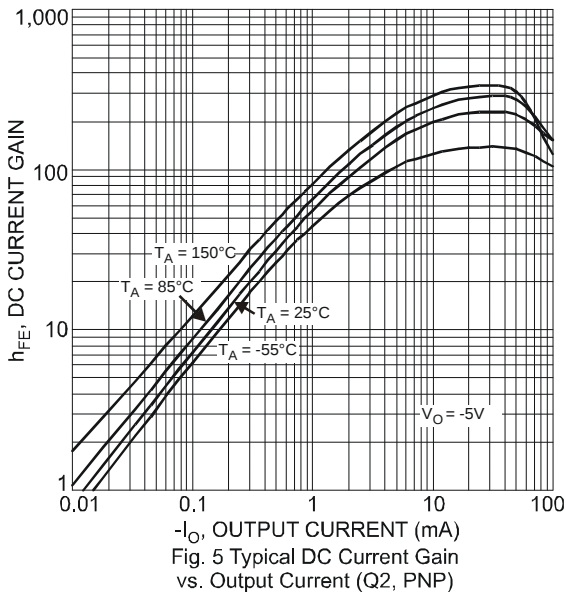


Fig. 4 Typical Input ON Voltage vs. Output Current (Q1, NPN)

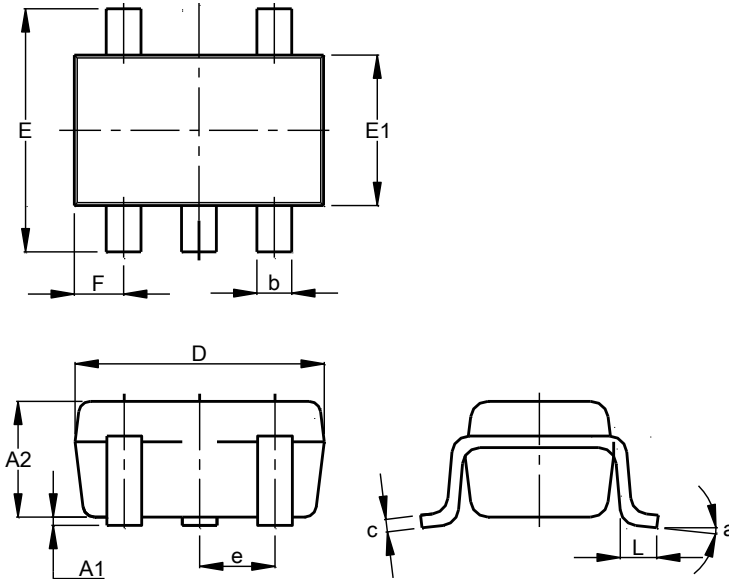
Typical Electrical Characteristics (Cont.) (@ $T_A = +25^\circ\text{C}$ unless otherwise specified.)



Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT353

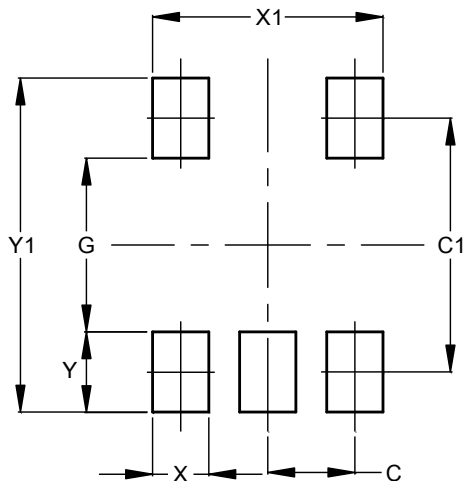


SOT353			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	1.00
b	0.10	0.30	0.25
c	0.10	0.22	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
F	0.40	0.45	0.425
L	0.25	0.40	0.30
a	0°	8°	--
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT353



Dimensions	Value (in mm)
C	0.650
C1	1.900
G	1.300
X	0.420
X1	1.720
Y	0.600
Y1	2.500

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